

# SANYO Semiconductors DATA SHEET

# LV8019LP — Forward/Reverse Motor Driver

### Overview

The LV8019LP is a forward/reverse motor driver.

### **Features**

- One H-bridge driver channel
- Provides a constant current output
- Built-in thermal shutdown circuit

### **Specifications**

**Maximum Ratings** at Ta = 25°C and SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Output block supply voltage	VM max		-0.5 to 8.4	V
Control block supply voltage	V <sub>CC</sub> max		-0.5 to 7.0	V
Constant current output block supply voltage	VRG max		-0.5 to 6.0	V
Maximum output current	I <sub>O</sub> max		1.0	Α
	I <sub>O</sub> peak1	t ≤ 200ms, f = 2Hz	3	Α
	I <sub>O</sub> peak2	t ≤ 10ms, f = 2Hz	5	Α
Input signal voltage	V <sub>IN</sub> max		-0.5 to V <sub>CC</sub> +0.5	Α
Allowable power dissipation	Pd max1	Independent IC	0.2	W
	Pd max2	When mounted on a circuit board *1	1.05	W
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

 $<sup>^{\</sup>star}$  : Specified substrate : 40×50×0.8mm³, glass epoxy four-layer (2S2P) board

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### LV8019LP

# **Recommended Operating Conditions** at Ta = 25°C and SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Output block supply voltage	VM		3.0 to 7.4	V
Control block supply voltage	V <sub>CC</sub>		2.7 to 6.0	V
Constant current output block supply voltage	VRGIN		1.5 to V <sub>CC</sub>	V
Input signal voltage	VIN		0 to V <sub>CC</sub>	V
Maximum input signal frequency	f <sub>max</sub>	Duty = 50%	100	kHz

# **Electrical Characteristics** Ta = 25 °C, $V_{CC} = VM = 5V$ , and SGND = PGND = 0V unless otherwise specified.

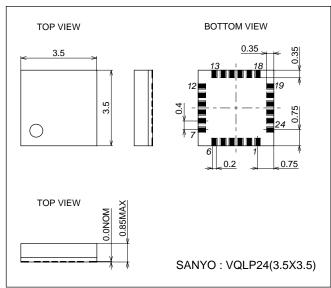
Parameter		Cumbal	Conditions		Unit		
		Symbol Conditions		min	typ	max	Unit
Standby mode output block current consumption		IMO	EN = 0V, IN1 = IN2 = ICTRL = 0V			1.0	μА
Control block current	Standby mode	Icco	EN = 0V, IN1 = IN2 = ICTRL = 0V		0	1.0	μΑ
consumption	Operation mode	Icc	EN = 5V		0.8	1.3	mA
High-level input vol	High-level input voltage		IN*	2.5		VCC	V
Low-level input volt	age	V <sub>IN</sub> L	IN*	0		8.0	V
High-level input cur	rrent	I <sub>IN</sub> H	IN*			1.0	μΑ
Low-level input cur	rent	I <sub>IN</sub> L	IN*	-1.0			μΑ
High-level EN pin c	High-level EN pin current		EN	15	25	35	μΑ
Low-level EN pin co	Low-level EN pin current		EN			1.0	μΑ
Output on	Output on 1		VM = 5V, sink + source		0.30	0.40	Ω
resistance 2		R <sub>ON</sub> 2	VM = 3V, sink + source		0.45	0.60	Ω
ISET setting resista	ance	RSET	Between ISET pin and SGND	80			Ω
ISET pin voltage		VISET	RSET > 80Ω	0.90	1.05	1.20	V
CC pin output satur	ration voltage	VCSAT	RSET = 150Ω *1			1.5	V
CC pin output leaka	CC pin output leakage current		CTRL = 0V			1.0	μΑ
Low voltage shutdown operation voltage		VLVD	V <sub>CC</sub> pin voltage detection	2.10	2.35	2.60	V
High-level output turn-on time		ТОН	The transition from 10% to 90% of the output amplitude *2		0.1	1.0	μs
Low-level output turn-on time		TOL	The transition from 90% to 10% of the output amplitude *2		0.2	2.0	μs
Thermal shutdown temperature		TSD	*2	150	180		°C
Thermal shutdown hysteresis		ΔTSD	*2		40		°C

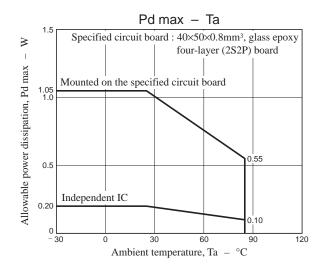
<sup>\*1 :</sup> Voltage between CC pin and ISET pin

 $<sup>\</sup>ensuremath{^{*}2}$  : Design guarantee: These characteristics are not measured.

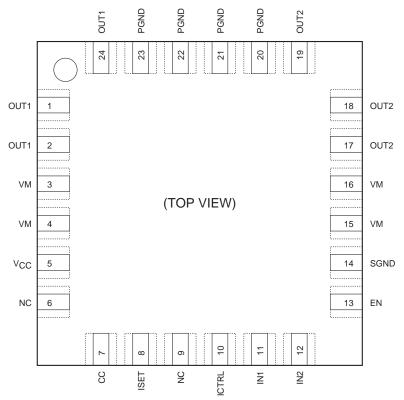
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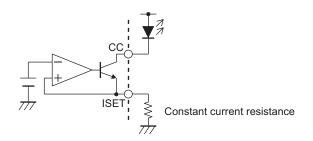




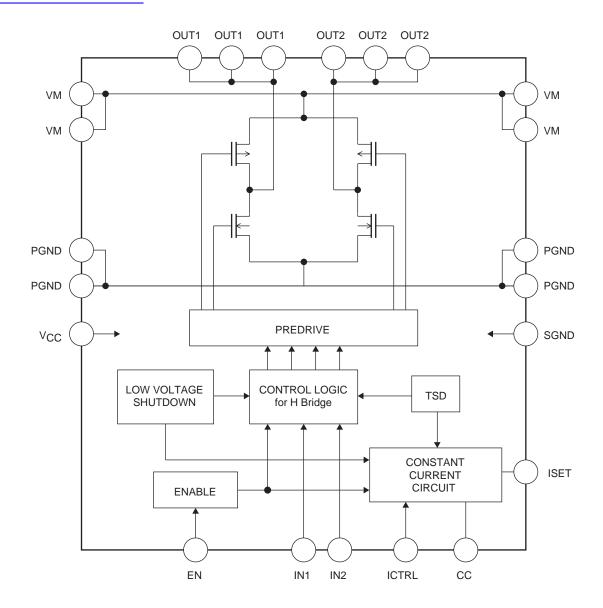
# **Pin Assignment**



### **Constant current output**



### Block Diagram 查询 LV80 9LP 供应商



### **Truth Table**

EN	IN1	IN2	CTRL	OUT1	OUT2	СС	Mode	
Н	Н	Н	X	L	L	Х	Break	
Н	Н	L	X	Н	L	Х	Forward	
Н	L	Н	Х	L	Н	Х	Reverse	
Н	L	L	Х	Z	Z	Х	Standby	
L	Х	Х	X	L	L	L	Standby	
Н	Х	Х	L	Х	Х	Z	Constant current output off	
Н	X	Х	Н	Х	Х	ON	Constant current output on	

H : High level

L : Low level

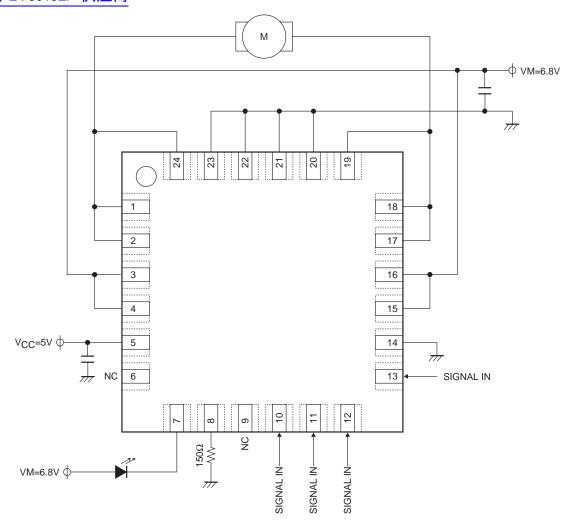
Z : Hi-impedance

X : Don't care

# LV8019LP

Pin Eunc	tions. c	2"供应宽	
Pin No.	Pin	Description	Equivalent circuit
11 12	IN1 IN2	Logic input 1 Logic input 2 The output is set by the combination of the input 1 and 2 states. See the truth table for details.  Controls the output on/off state of the constant current block.	VCC $10k\Omega$
13	EN	EN pin Controls the on/off state of the H-bridge output (OUT1 and OUT2) and the constant current output. See the truth table for details.	$V_{CC}$ $10k\Omega$ $200k\Omega$ S-GND
1, 2, 24, 17, 18, 19	OUT1 OUT2	Output 1 Output 2 The source side is a p-channel transistor and sink side is an n-channel transistor.	VM OUT* PGND
7 8	CC ISET	Constant current output Constant current setting The output current (CC) is set by connecting a resistor between the ISET pin and ground.	VCC CC SGND VCC ISET SGND
5	VCC	Signal system power supply	Vcc
3, 4, 15, 16	VM	Power system power supply	VM ()———
14	SGND	Signal system ground	SGND —
21, 22, 23	PGND	Power system ground	PGND

## Application Example



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